Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Vishay Semiconductor/Diodes Division
S1PB-E3/85A

For any questions, you can email us directly:
sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite
Datasheet of S1PB-E3/85A - DIODE GEN PURP 100V 1A DO220AA
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

New Product

S1PB thru S1PM

Vishay General Semiconductor

High Current Density Surface Mount Glass-Passivated Rectifiers

eSMP™ Series

DO-220AA (SMP)

FEATURES

- Very low profile - typical height of 1.0 mm
- Ideal for automated placement
- Glass passivated chip junction
- Low forward voltage drop
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

RoHS COMPLIANT

TYPICAL APPLICATIONS

General purpose, polarity protection, and rail-to-rail protection in both consumer and automotive applications.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	1 A
V_{RRM}	100 V to 1000 V
I_R	1 µA
V_F	0.95 V
T_J max.	150 °C

MECHANICAL DATA

Case: DO-220AA (SMP)
Epoxy meets UL 94V-0 flammability rating
Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102
E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test
Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Device marking code		SB	SD	SG	SJ	SK	SM	
Maximum repetitive peak reverse voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	100	200	400	600	800	1000	V
Average forward current	$I_{F(AV)}$	1.0						A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	30						A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150						°C

New Product

S1PB thru S1PM

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)										
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**S1PB**	**S1PD**	**S1PG**	**S1PJ**	**S1PK**	**S1PM**	**UNIT**
Maximum instantaneous forward voltage (1)	I_F = 1.0 A I_F = 1.0 A	T_J = 25 °C T_J = 125 °C	V_F	1.1 0.95						V
Maximum reverse current (1)	rated V_R	T_J = 25 °C T_J = 125 °C	I_R	1.0 50				1.0 100		µA
Typical reverse recovery time	I_F = 0.5 A, I_R = 1.0 A, I_{rr} = 0.25 A		t_{rr}	1.8						µs
Typical junction capacitance time	4.0 V, 1 MHz		C_J	6.0						pF

Note:
(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)								
PARAMETER	**SYMBOL**	**S1PB**	**S1PD**	**S1PG**	**S1PJ**	**S1PK**	**S1PM**	**UNIT**
Typical thermal resistance (1)	$R_{\theta JA}$ $R_{\theta JL}$ $R_{\theta JC}$	105 15 20						°C/W

Note:
(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas. $R_{\theta JC}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)				
PREFERRED P/N	**UNIT WEIGHT (g)**	**PREFERRED PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
S1PJ-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel
S1PJ-E3/85A	0.024	85A	10000	13" diameter plastic tape and reel
S1PJHE3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel
S1PJHE3/85A (1)	0.024	85A	10000	13" diameter plastic tape and reel

Note:
(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

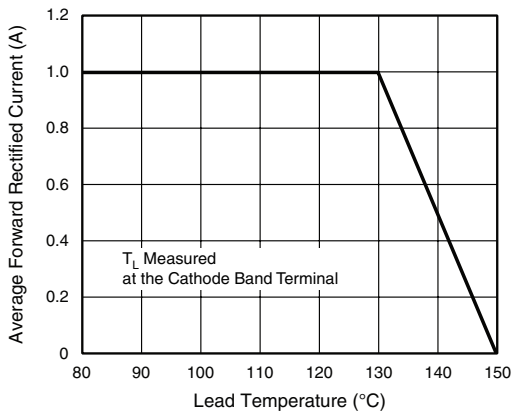


Figure 1. Maximum Forward Current Derating Curve

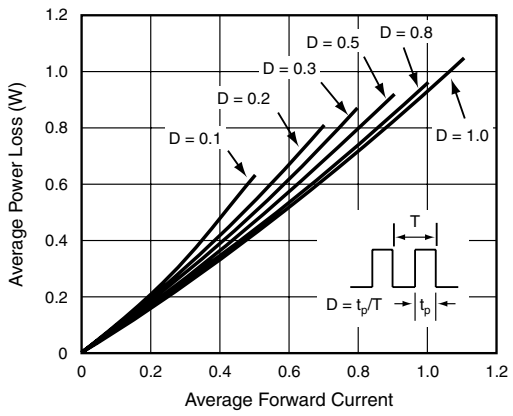


Figure 2. Forward Power Loss Characteristics

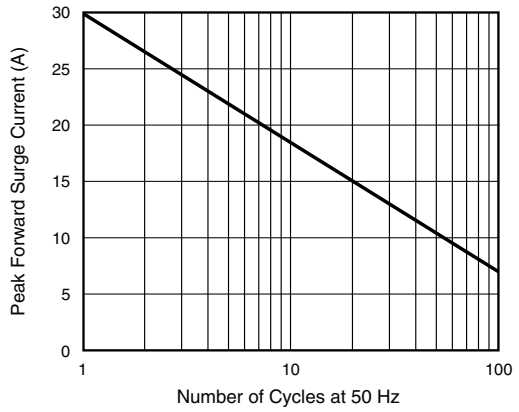


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

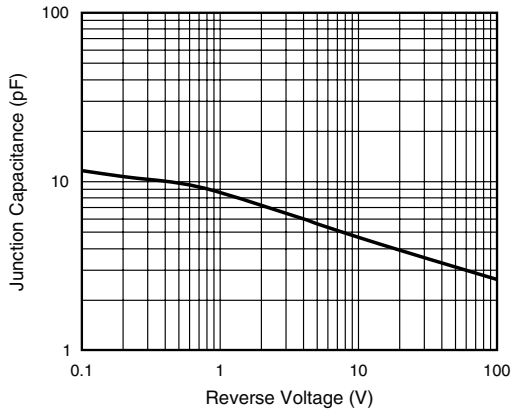


Figure 6. Typical Junction Capacitance

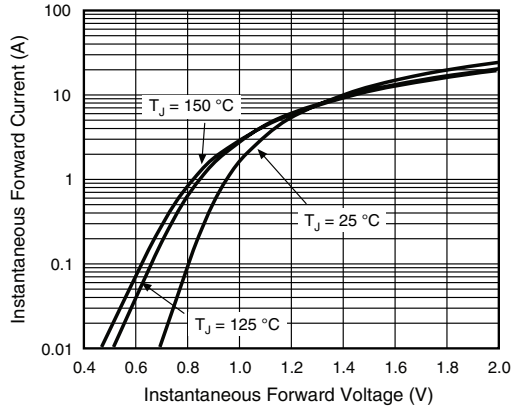


Figure 4. Typical Instantaneous Forward Characteristics

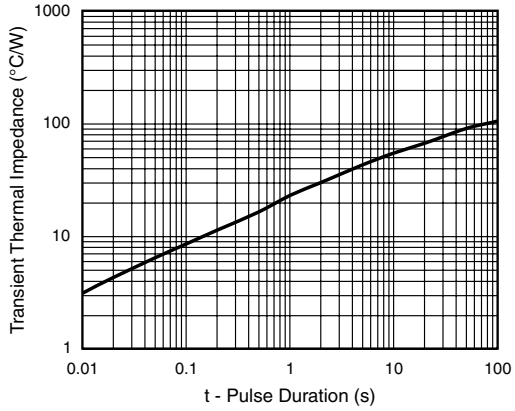


Figure 7. Typical Transient Thermal Impedance

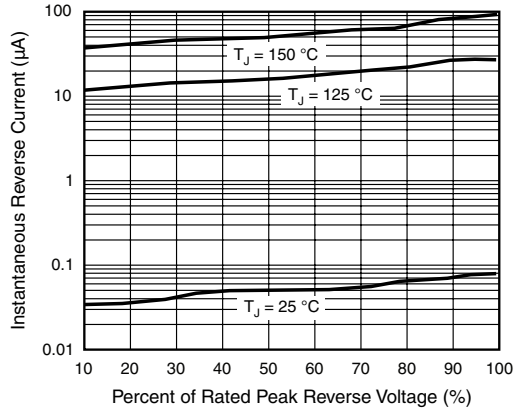


Figure 5. Typical Reverse Leakage Characteristics

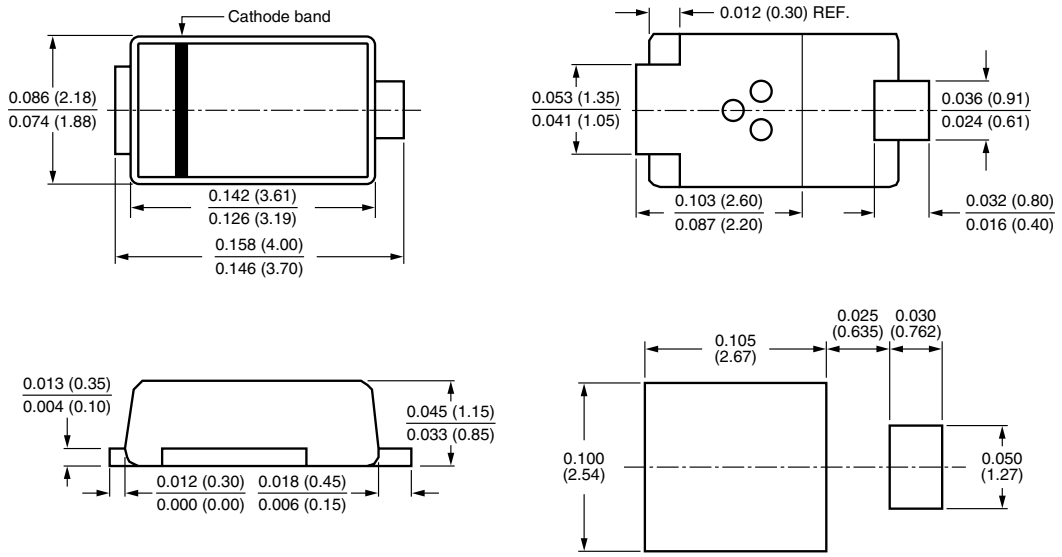
New Product

S1PB thru S1PM

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP)



Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite
Datasheet of S1PB-E3/85A - DIODE GEN PURP 100V 1A DO220AA
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

Legal Disclaimer Notice

Vishay

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.